

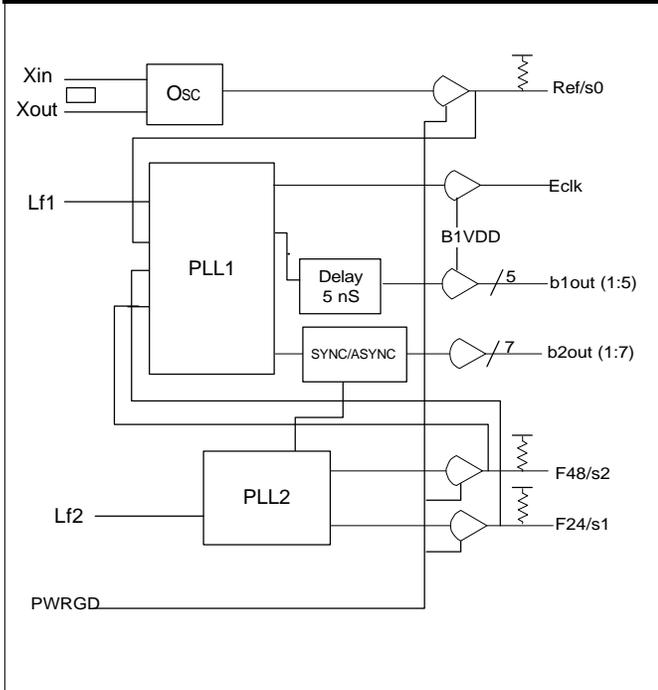
Preliminary
June 1996

PLL FREQUENCY SYNTHESIZER
CMOS LSI

PRODUCT FEATURES

- Supports PCI system board designs P54, P55, and P6
- buffers
- An early host clock, 5 low skew host clocks and 7 low skew PCI clocks
- Supports 5V or 3.3V or mixed supply.
- 60 mA buffer switching current
- 28 Pin SSOP package for minimum board

BLOCK DIAGRAM



PRODUCT DESCRIPTION

The IMISC605 provides the clocks and the low skew distribution buffers required to drive the Pentium™ CPU and PCI busses. Mixed supply option for P55/54 applications. Fixed 24 and 12 Mhz for floppy and keyboard.

APPLICATIONS

60 mA of switching current is provided on all outputs at B1VDD = VDD = 5V.

3.3V operating modes support new low voltage components on the CPU bus. Operating the B1 buffer at 3.3V (B1VDD) and routing the CPU clock through B1 distributes a 3.3V signal to the CPU bus. The outputs provide 30 mA switching current.

FREQUENCY TABLE

SELECT			OUTPUTS (MHz)	
F12/S2	F24/S1	Ref/S0	ECLK ⁺	B2out [*]
0	0	0	50	a.32
0	0	1	55	a.32
0	1	0	75	a.32
0	1	1	75	37.5
1	0	0	50	25
1	0	1	55	27.5
1	1	0	60	30
1	1	1	66.6	33.3

⁺ ECLK = B1out^{*}

a.32 = asynchronous 32 MHz.

Preliminary
June 1996

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PIN DESCRIPTION

Xin Xout - These pins form an on-chip reference oscillator when connected to terminals of an external parallel resonant crystal (nominally 14.318 MHz). OSCin may also serve as input for an externally generated reference signal.

ECLK - Early Hose Clock output. When PWRGD is low, this pin is low.

B1out* - Delayed buffered outputs of ECLK.

B2out* - Buffered outputs for PCI bus. Synchronous to ECLK.

F24/S1 - When PWRGD is low this pin is used as an input select line, S1. When PWRGD is high this pin is 24 MHz output. This pin has an internal pull-up.

F12/S2 - When PWRGD is low this pin is used as an input select line, S2. When PWRGD is high this pin is 12 MHz output. This pin has an internal pull-up.

PWRGD - Logic low on this input tristates the fixed frequency outputs and forces Eclk, B1out*, and B2out* outputs to a low state synchronously. When logic transitions to high, the select is latched, the fixed frequency outputs are enabled, and Eclk, B1out*, B2out* toggle synchronously at the rising edge.

Ref/S0 - When PWRGD is low this pin is used as an input select line, S0. When PWRGD is high this pin is a reference output of the crystal input. This pin has an internal pull-up.

LF1 and LF2 - These are the loop filter pins for the clock generators. A 0.1 μ F capacitor should be connected from each pin to AVSS. Grounding LF puts PLL in low power mode.

VSS - Circuit ground.

VDD - Positive power supply.

AVSS - Analog circuit ground.

AVDD - Analog positive power supply.

B1VDD - 3.3V/5V logic level control for ECLK and B1out* outputs.

Note: always B1VDD \leq VDD.

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Voltage Relative to VSS: -0.3V
 Voltage Relative to VDD: 0.3V
 Storage Temperature: -65°C to 150°C
 Ambient Temperature: -55°C to +125°C
 Maximum Supply Voltage: 6V

application of any voltage higher than the maximum rated voltages to its circuit. For proper operation, Vin and Vout should be constrained to the range:

$$V_{ss} < (V_{in} \text{ or } V_{out}) < V_{DD}$$

This device contains circuitry to protect the inputs against damage due to high static voltages or electric field; however, precautions should be taken to avoid

Unused inputs must always be tied to an appropriate logic voltage level (either Vss or VDD).

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Typ	Max	Units	Conditions
Input Low Voltage	V _{IL}	-	-	0.8	V _{dc}	PWRGD, F12/S2, F24/S1, Ref/S0
Input High Voltage	V _{IH}	2.0	-	-	V _{dc}	
Input Low Current with Pull-up or Pull-down	I _{IL} , I _{IH}	-	-	5 ± 50	µA	
Output Low Voltage I _{OL} = 6mA	V _{OL}	-	-	0.4	V _{dc}	ECLK and B1out*
Output High Voltage I _{OH} = 6mA	V _{OH}	2.4	-	-	V _{dc}	
Output Low Voltage I _{OL} = 12mA	V _{OL}	-	-	0.4	V _{dc}	All other outputs
Output High Voltage I _{OH} = 12mA	V _{OH}	2.4	-	-	V _{dc}	
Tri-State leakage Current	I _{OZ}	-	-	10	µA	LF1, LF2, and tristate outputs
Dynamic Supply Current	I _{DD}	-	-	TBD	mA	ECLK = 50 MHz
Static Supply Current	I _{DD}	-	TBD	-	µA	LF1 = LF2 = 0, Xin = 1
Short Circuit Current	I _{OS}	25	-	-	mA	1 output at a time - max 30 sec.
Power supply condition		VDD=AVDD= 5V ± 10% B1VDD = 3.3V ± 10%. TA = 0°C to 70°C				

Preliminary
June 1996

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SWITCHING CHARACTERISTICS

Characteristic	Symbol	Min	Typ	Max	Units	Conditions
Output Rise (0.8V - 2.0V) and Fall (2.0V-0.8V) time	tTLH,	-	-	1.5	nS	15 pF load. B1out* + ECLK
	tTHL	-	-	1.5	nS	15pF load. All other outputs
Output duty cycle		45	50	55	%	Measured at 1.5V, 15 pF load
B1out*-Skew	t1SKW	-	-	250	pS	Measured at 1.5V
B2out*-Skew	t2SKW	-	-	500	pS	Measured at 1.5V
B1out* - B2out* offset	toffset	0	-	4	nS	Measured at 1.5V
ECLK to B1out* delay	tdelay		6			Measured at 1.5V
ΔPeriod Adjacent Cycles	ΔP	-	± 200	-	pS	Measured at 1.5V on ECLK
Jitter Absolute	tjab	-	± 250		pS	Measured at 1.5V on ECLK
Power supply condition		VDD=AVDD= 5V ± 10% B1VDD = 3.3V ± 10%. TA = 0°C to 70°C				

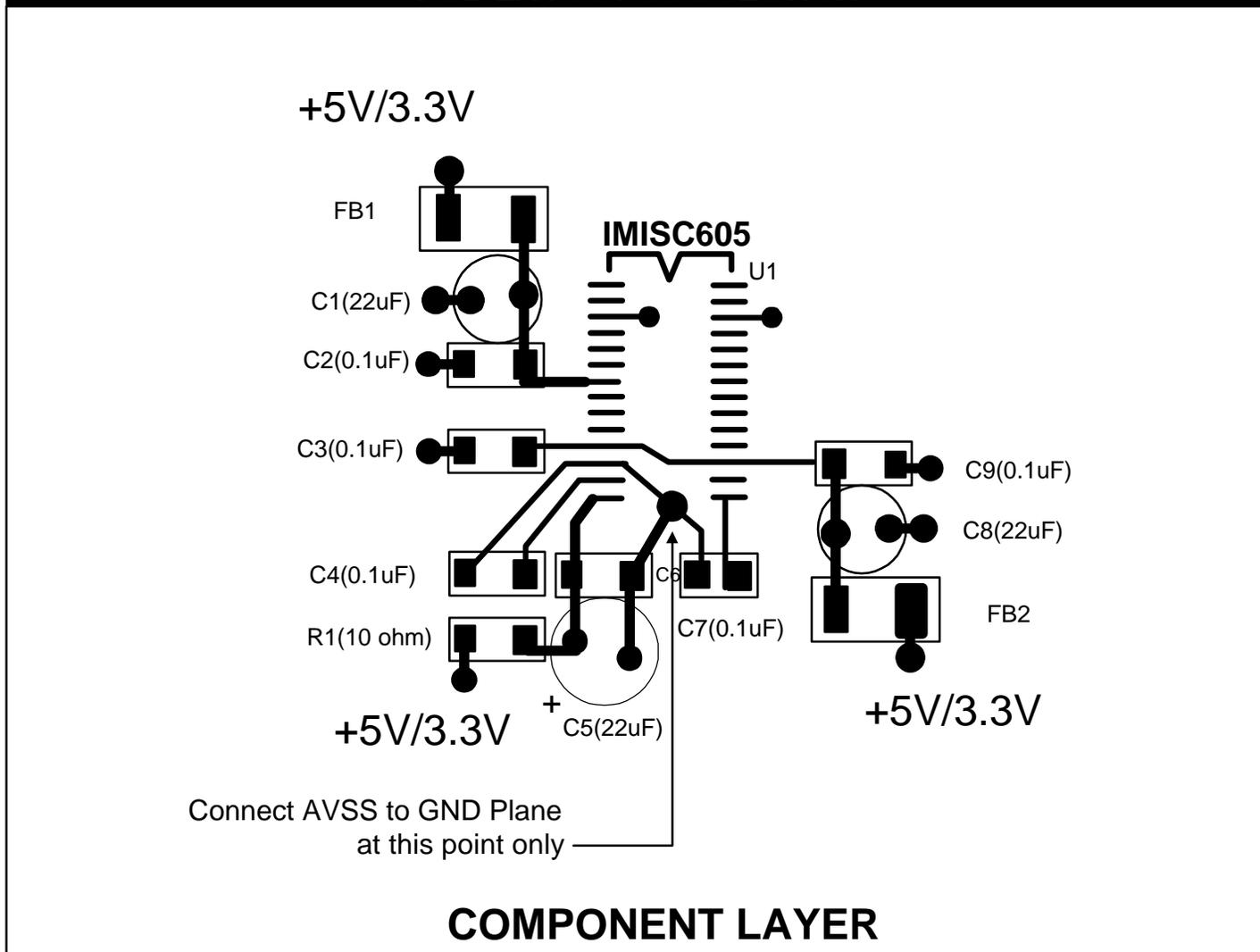
CONNECTION DIAGRAMS

Xin	<input type="checkbox"/>	1	28	<input type="checkbox"/>	Ref/S0
Xout	<input type="checkbox"/>	2	27	<input type="checkbox"/>	F24/S1
VSS	<input type="checkbox"/>	3	26	<input type="checkbox"/>	VSS
Eclk	<input type="checkbox"/>	4	25	<input type="checkbox"/>	B2out1
B1out1	<input type="checkbox"/>	5	24	<input type="checkbox"/>	B2out2
B1out2	<input type="checkbox"/>	6	23	<input type="checkbox"/>	B2out3
B1vdd	<input type="checkbox"/>	7	22	<input type="checkbox"/>	F12/S2
B1out3	<input type="checkbox"/>	8	21	<input type="checkbox"/>	B2out4
B1out4	<input type="checkbox"/>	9	20	<input type="checkbox"/>	B2out5
B1out5	<input type="checkbox"/>	10	19	<input type="checkbox"/>	B2out6
VDD	<input type="checkbox"/>	11	18	<input type="checkbox"/>	B2out7
AVSS	<input type="checkbox"/>	12	17	<input type="checkbox"/>	VDD
Lf1	<input type="checkbox"/>	13	16	<input type="checkbox"/>	PWRGD
AVDD	<input type="checkbox"/>	14	15	<input type="checkbox"/>	Lf2

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PCB LAYOUT SUGGESTION



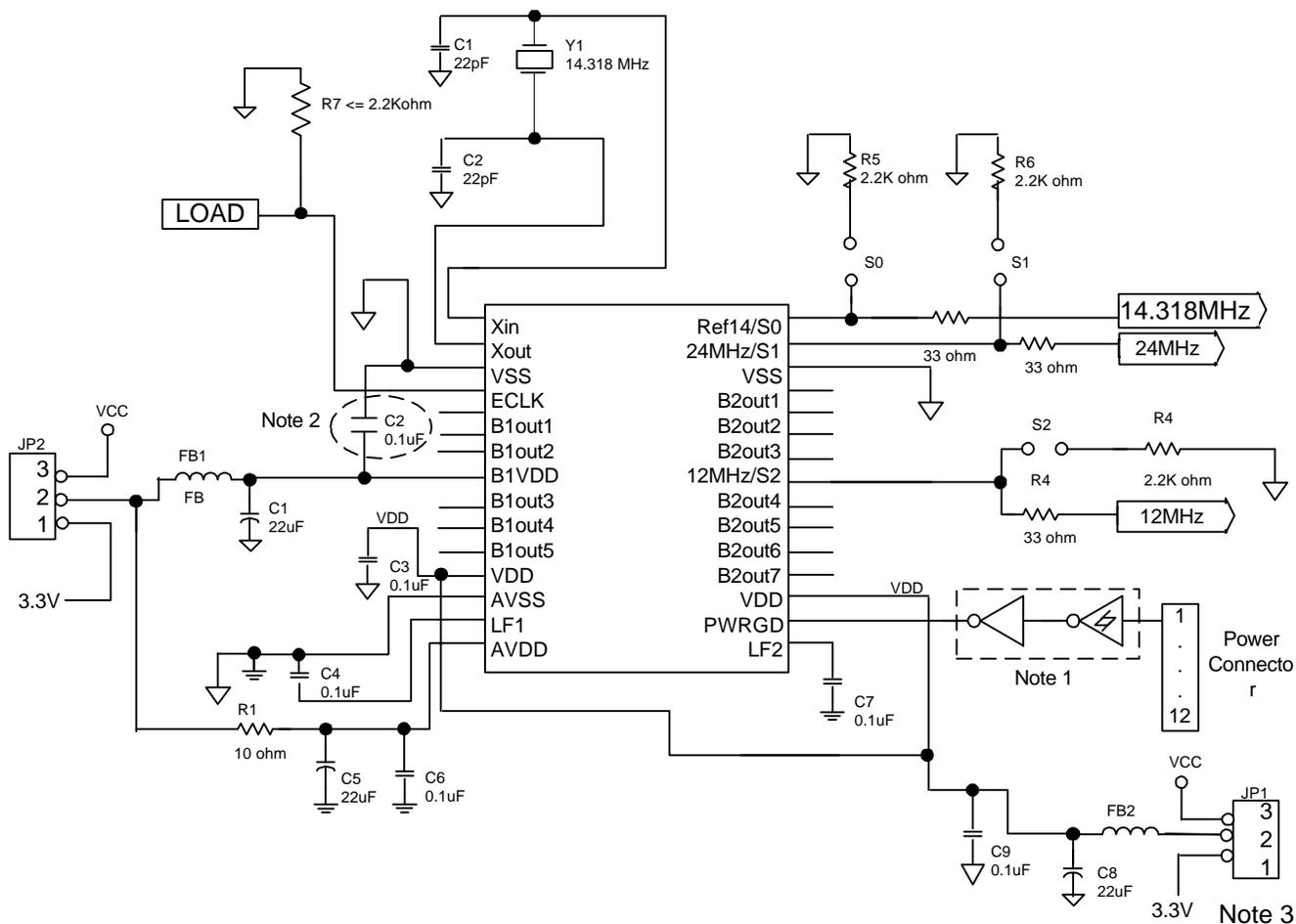
NOTES

1. Power supply bypass caps (0.1 μ F and 22 μ F) must be positioned close to VDD pins to be effective.
2. LF caps must be low leakage, such as multilayer ceramic Z5U or X7R material.

Preliminary
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APPLICATION SUGGESTION (Update)



Note 1: Buffers with Schmitt-Trigger will be internal in SC605.

Note 2: The Capacitor (C2) should be closer to Pin 7 and Pin 3.

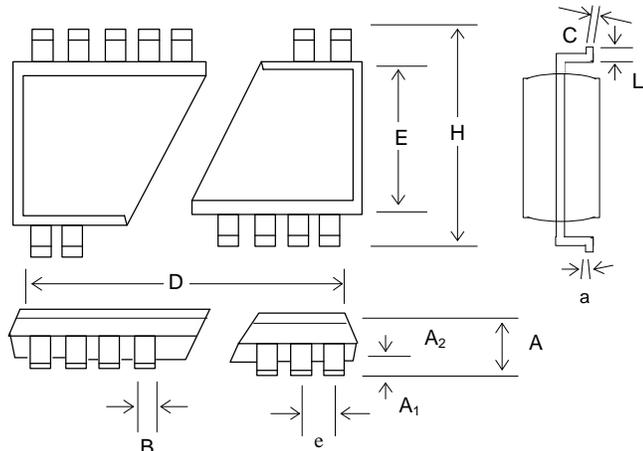
Note 3: Shunting to pin 1 and 2 on JP1 is only supported on SC605.

1. For 2.5 ns buffer delay place a resistor $R7 (\leq 5 \text{ k}\Omega)$. For SC605C the delay will be 3.0 ns.
2. For a 4.5 ns delay remove R7 and leave open. For SC605C the delay will be 6.0 ns.

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PACKAGE DRAWING AND DIMENSIONS



28 PIN SSOP OUTLINE DIMENSIONS

SYMBOL	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.068	0.073	0.078	1.73	1.86	1.99
A ₁	0.002	0.005	0.008	0.05	0.13	0.21
A ₂	0.066	0.068	0.070	1.68	1.73	1.78
B	0.010	0.012	0.015	0.25	0.30	0.38
C	0.005	0.006	0.009	0.13	0.15	0.22
D	0.397	0.402	0.407	10.07	10.20	10.33
E	0.205	0.209	0.212	5.20	5.30	5.38
e	0.0256 BSC			0.65 BSC		
H	0.301	0.307	0.311	7.65	7.80	7.90
a	0°	4°	8°	0°	4°	8°
L	0.022	0.030	0.037	0.55	0.75	0.95

ORDERING INFORMATION

Part Number	Package Type	Production Flow
IMISC605AYB	28 PIN SSOP	Commercial, 0°C to 70°C

Marking: IMI

SC605AYB
Date Code, Lot #

IMISC605AYB

